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Dual 2-to-4 line decoder/demultiplexer

Rev. 1 — 5 June 2013

Product data sheet

1. General description

The 74AHC139-Q100; 74AHCT139-Q100 is a high-speed Si-gate CMOS device and is pin compatible with Low-power Schottky TTL (LSTTL). It is specified in compliance with JEDEC standard No. 7A.

The 74AHC139-Q100; 74AHCT139-Q100 is a high-speed, dual 2-to-4 line decoder/demultiplexer. This device has two independent decoders. Each decoder accepts two binary weighted inputs (nA0 and nA1) and provides four mutually exclusive active LOW outputs (n \overline{Y} 0 to n \overline{Y} 3). Each decoder has an active LOW enable input (n \overline{E}). When n \overline{E} is HIGH, every output is forced HIGH. The enable input can be used as the data input for a 1-to-4 demultiplexer application.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Balanced propagation delays
- All inputs have Schmitt-trigger actions
- Inputs accept voltages higher than V_{CC}
- Input levels:
 - For 74AHC139-Q100: CMOS level
 - For 74AHCT139-Q100: TTL level
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Multiple package options

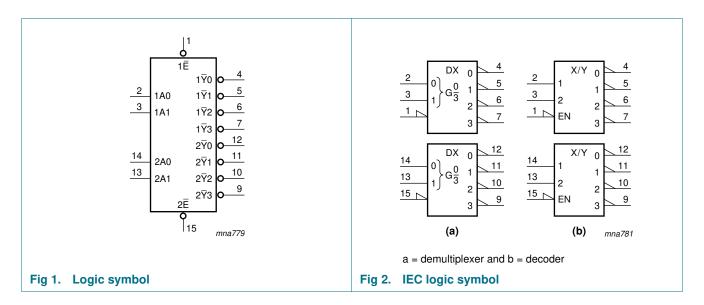


Dual 2-to-4 line decoder/demultiplexer

3. Ordering information

Table 1. Ordering in	nformation			
Type number	Package			
	Temperature range	Name	Description	Version
74AHC139-Q100				
74AHC139D-Q100	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74AHC139PW-Q100	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1
74AHCT139-Q100				
74AHCT139D-Q100	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74AHCT139PW-Q100	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1

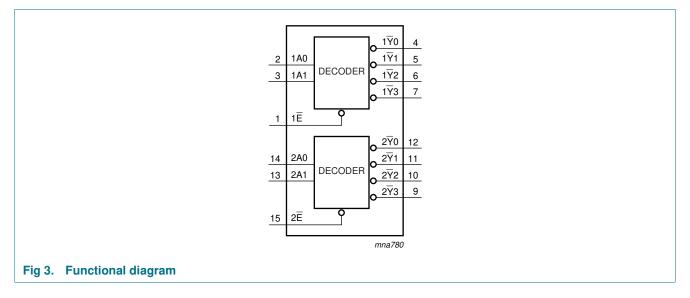
4. Functional diagram



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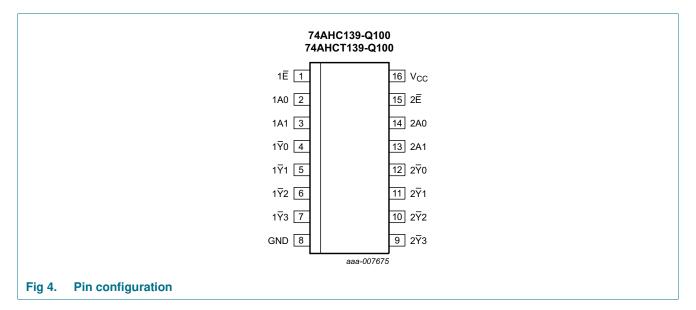
74AHC139-Q100; 74AHCT139-Q100

Dual 2-to-4 line decoder/demultiplexer



5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2.	Pin description	
Symbol	Pin	Description
1Ē	1	enable input (active LOW)
1A0	2	address input
1A1	3	address input
1 <u>7</u> 0	4	output
1 <u></u> 1	5	output

74AHC_AHCT139_Q100

Product data sheet

Dual 2-to-4 line decoder/demultiplexer

Table 2.	Pin description	continued
Symbol	Pin	Description
1 <u>7</u> 2	6	output
1 <u>7</u> 3	7	output
GND	8	ground (0 V)
2 <u>7</u> 3	9	output
2 <u>7</u> 2	10	output
2 <u>7</u> 1	11	output
2 <u>7</u> 0	12	output
2A1	13	address input
2A0	14	address input
2E	15	enable input (active LOW)
V _{CC}	16	supply voltage

6. Functional description

Table 3.Function table

Control	Input	ut		Output					
nE	nA0	nA1	n Y 0	n¥1	n¥2	n¥3			
Н	Х	Х	Н	Н	Н	Н			
L	L	L	L	Н	Н	Н			
	Н	L	Н	L	Н	Н			
	L	Н	Н	Н	L	Н			
	Н	Н	Н	Н	Н	L			

[1] H = HIGH voltage level;

L = LOW voltage level;

X = don't care.

7. Limiting values

Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7.0	V
VI	input voltage		-0.5	+7.0	V
I _{IK}	input clamping current	$V_{I} < -0.5 V$	<u>[1]</u> –20	-	mA
I _{OK}	output clamping current	$V_O < -0.5 \ V$ or $V_O > V_{CC}$ + 0.5 V	[1] -20	+20	mA
I _O	output current	$V_{\rm O} = -0.5$ V to (V_{\rm CC} + 0.5 V)	-25	+25	mA
I _{CC}	supply current		-	+75	mA
I _{GND}	ground current		-75	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \text{ °C to } +125 \text{ °C}$	[2] _	500	mW
-					

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

74AHC_AHCT139_Q100
Product data sheet

Dual 2-to-4 line decoder/demultiplexer

74AHC_AHCT139_Q100

Dual 2-to-4 line decoder/demultiplexer

8. Recommended operating conditions

Table 5.	Operating conditions					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
74AHC1	39-Q100					
V _{CC}	supply voltage		2.0	5.0	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage		0	-	V_{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 3.0 V \text{ to } 3.6 V$	-	-	100	ns/V
		$V_{CC} = 4.5 V \text{ to } 5.5 V$	-	-	20	ns/V
74AHCT	139-Q100					
V _{CC}	supply voltage		4.5	5.0	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage		0	-	V_{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	$V_{CC} = 4.5 \text{ V}$ to 5.5 V	-	-	20	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74AHC1	39-Q100									
VIH	HIGH-level	$V_{CC} = 2.0 V$	1.5	-	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 3.0 V	2.1	-	-	2.1	-	2.1	-	V
		$V_{CC} = 5.5 V$	3.85	-	-	3.85	-	3.85	-	V
V _{IL}	LOW-level	V _{CC} = 2.0 V	-	-	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 3.0 V	-	-	0.9	-	0.9	-	0.9	V
	V _{CC} = 5.5 V	-	-	1.65	-	1.65	-	1.65	V	
V _{OH} HIGH-level	$V_I = V_{IH}$ or V_{IL}									
	output voltage	$I_{O} = -50 \ \mu A; V_{CC} = 2.0 \ V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_{O} = -50 \ \mu A; V_{CC} = 3.0 \ V$	2.9	3.0	-	2.9	-	2.9	-	V
		$I_{O} = -50 \ \mu A; V_{CC} = 4.5 \ V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.58	-	-	2.48	-	2.40	-	V
		$I_{O} = -8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.94	-	-	3.80	-	3.70	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_{O} = 50 \ \mu A; \ V_{CC} = 2.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_{O} = 50 \ \mu A; \ V_{CC} = 3.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_{O} = 50 \ \mu A; \ V_{CC} = 4.5 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_{O} = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.36	-	0.44	-	0.55	V
		I _O = 8.0 mA; V _{CC} = 4.5 V	-	-	0.36	-	0.44	-	0.55	V

Dual 2-to-4 line decoder/demultiplexer

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	-40 °C to	o +125 °C	Unit
			Min	Тур	Мах	Min	Max	Min	Max	-
I	input leakage current	$V_1 = 5.5 V \text{ or GND};$ $V_{CC} = 0 V \text{ to } 5.5 V$	-	-	0.1	-	1.0	-	2.0	μA
I _{CC}	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = V_{CC} \text{ or } GND; \ I_{O} = 0 \ A; \\ V_{CC} = 5.5 \ V \end{array}$	-	-	4.0	-	40	-	80	μA
Cı	input capacitance	$V_{I} = V_{CC}$ or GND	-	3	10	-	10	-	10	pF
Co	output capacitance		-	4	-	-	-	-	-	pF
74AHCT	139-Q100									
V _{IH}	HIGH-level input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	-	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	V_{CC} = 4.5 V to 5.5 V	-	-	0.8	-	0.8	-	0.8	V
V _{OH}		$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = -50 μA	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -8.0 mA	3.94	-	-	3.80	-	3.70	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = 50 μA	-	0	0.1	-	0.1	-	0.1	V
		I _O = 8.0 mA	-	-	0.36	-	0.44	-	0.55	V
l _l	input leakage current	$V_I = 5.5 V \text{ or GND};$ $V_{CC} = 0 V \text{ to } 5.5 V$	-	-	0.1	-	1.0	-	2.0	μ A
I _{CC}	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = V_{CC} \text{ or } GND; \ I_{O} = 0 \ A; \\ V_{CC} = 5.5 \ V \end{array}$	-	-	4.0	-	40	-	80	μ A
∆l _{CC}	additional supply current	per input pin; $V_I = V_{CC} - 2.1$ V; other pins at V_{CC} or GND; $I_O = 0$ A; $V_{CC} = 4.5$ V to 5.5 V	-	-	1.35	-	1.5	-	1.5	mA
Cı	input capacitance	$V_I = V_{CC}$ or GND	-	3	10	-	10	-	10	pF
C _O	output capacitance		-	4	-	-	-	-	-	pF

Table 6. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Dual 2-to-4 line decoder/demultiplexer

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 7.

Symbol	Parameter	Conditions			25 °C		–40 °C t	o +85 °C	–40 °C te	o +125 °C	Unit
				Min	Typ <mark>[1]</mark>	Max	Min	Max	Min	Max	
74AHC1	39-Q100	'									
t _{pd}		nAn to nYn; see <u>Figure 5</u>	[2]								
	delay	$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$									
		C _L = 15 pF		-	5.5	11.0	1.0	13.0	1.0	14.0	ns
		C _L = 50 pF		-	7.9	14.5	1.0	16.5	1.0	18.5	ns
		$V_{CC} = 4.5 \text{ V} \text{ to } 5.5 \text{ V}$									
		C _L = 15 pF		-	3.9	7.2	1.0	8.5	1.0	9.0	ns
		C _L = 50 pF		-	5.6	9.2	1.0	10.5	1.0	11.5	ns
		nE to nYn; see Figure 6	[2]								
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$									
		C _L = 15 pF		-	4.8	9.2	1.0	11.0	1.0	11.5	ns
		C _L = 50 pF		-	6.9	12.7	1.0	14.5	1.0	16.0	ns
		$V_{CC} = 4.5 \text{ V} \text{ to } 5.5 \text{ V}$									
		C _L = 15 pF		-	3.4	6.3	1.0	7.5	1.0	8.0	ns
		C _L = 50 pF		-	4.9	8.3	1.0	9.5	1.0	10.5	ns
C _{PD}	power dissipation capacitance	$f_i = 1 \text{ MHz}; V_1 = \text{GND to } V_{\text{CC}}$	[3]	-	26	-	-	-	-	-	pF
74AHCT	139-Q100; V _C	_C = 4.5 V to 5.5 V									
t _{pd}		nAn to nYn; see <u>Figure 5</u>	[2]								
	delay	C _L = 15 pF		-	4.7	7.2	1.0	8.5	1.0	9.0	ns
		$C_L = 50 \text{ pF}$		-	6.5	9.2	1.0	10.5	1.0	11.5	ns
		nE to nYn; see Figure 6	[2]								
		C _L = 15 pF		-	3.6	6.3	1.0	7.5	1.0	8.0	ns
		C _L = 50 pF		-	5.2	8.3	1.0	9.5	1.0	10.5	ns
C _{PD}	power dissipation capacitance	$f_i = 1 \text{ MHz}; V_I = \text{GND to } V_{\text{CC}}$	<u>[3]</u>	-	23	-	-	-	-	-	pF

[1] Typical values are measured at nominal supply voltage (V_{CC} = 3.3 V and V_{CC} = 5.0 V).

[2] t_{pd} is the same as t_{PLH} and t_{PHL} .

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \Sigma (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

 C_L = output load capacitance in pF;

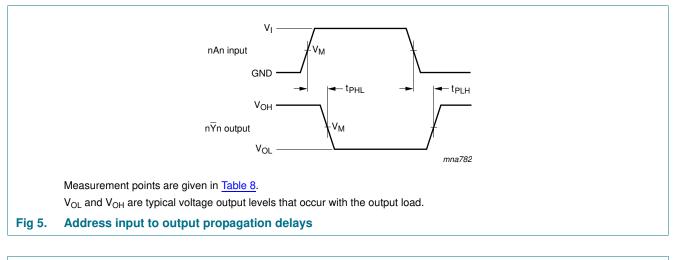
V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}{}^2 \times f_o)$ = sum of the outputs.

Dual 2-to-4 line decoder/demultiplexer

11. Waveforms



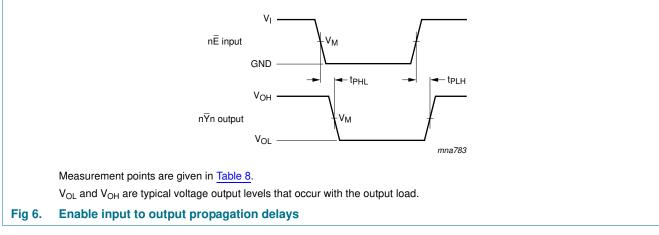


Table 8.Measurement points

Туре	Input	Output
	V _M	V _M
74AHC139-Q100	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
74AHCT139-Q100	1.5 V	$0.5 \times V_{CC}$

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74AHC139-Q100; 74AHCT139-Q100

Dual 2-to-4 line decoder/demultiplexer

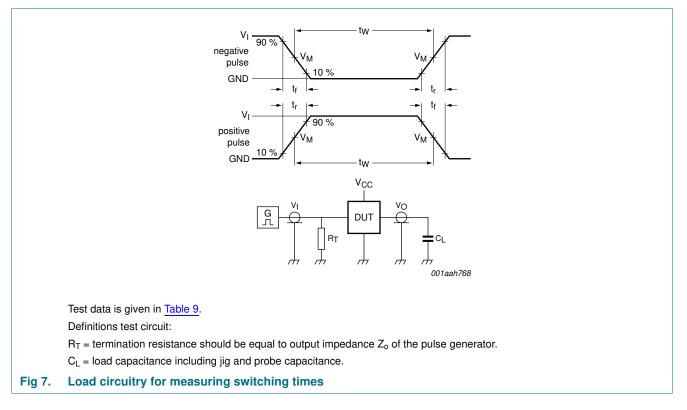


Table 9. Test data

Туре	Input Lo		Load	Test
	VI	t _r , t _f	CL	
74AHC139-Q100	V _{CC}	≤ 3.0 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}
74AHCT139-Q100	3.0 V	≤ 3.0 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}

Dual 2-to-4 line decoder/demultiplexer

12. Package outline

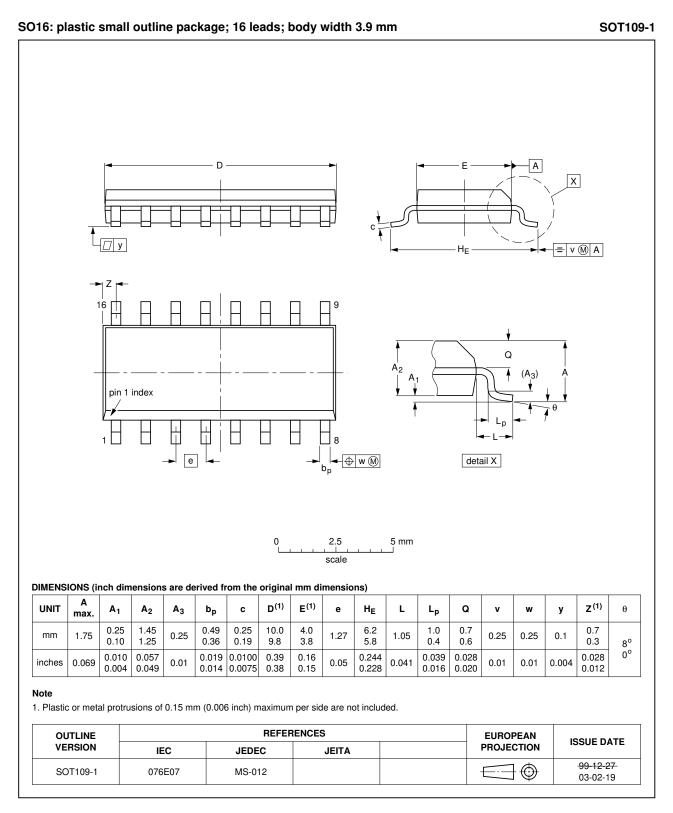


Fig 8. Package outline SOT109-1 (SO16)

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74AHC AHCT139 Q100

Dual 2-to-4 line decoder/demultiplexer

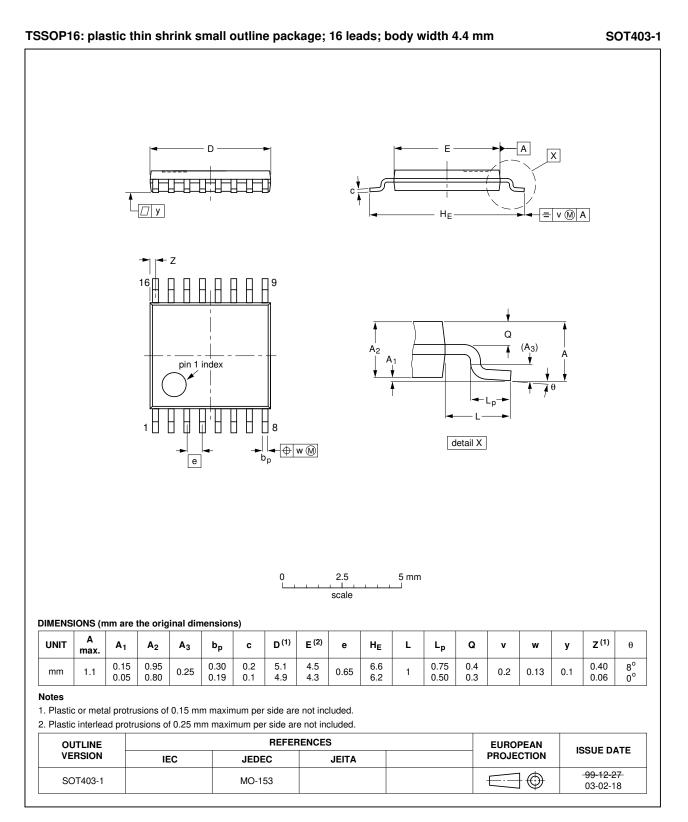


Fig 9. Package outline SOT403-1 (TSSOP16)

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74AHC_AHCT139_Q100

Dual 2-to-4 line decoder/demultiplexer

13. Abbreviations

Table 10.	Abbreviations
Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
LSTTL	Low-power Schottky Transistor-Transistor Logic
MIL	Military
MM	Machine Model

14. Revision history

Table 11. Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
74AHC_AHCT139_Q100 v.1	20130605	Product data sheet	-	-

Dual 2-to-4 line decoder/demultiplexer

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Dual 2-to-4 line decoder/demultiplexer

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Date of release: 5 June 2013 Document identifier: 74AHC_AHCT139_Q100